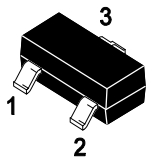
LBSS84LT1G
S-LBSS84LT1G

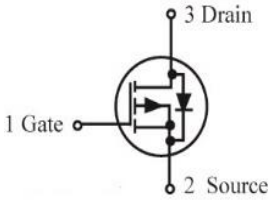
Power MOSFET
130 mA, 50V P–Channel SOT-23

1. FEATURES

- We declare that the material of product compliance with RoHS requirements and Halogen Free.
- S- prefix for automotive and other applications requiring unique site and control change requirements; AEC-Q101 qualified and PPAP capable.
- Energy efficient



SOT23(TO-236)



2. DEVICE MARKING AND ORDERING INFORMATION

Device	Marking	Shipping
LBSS84LT1G	PD	3000/Tape&Reel
LBSS84LT3G	PD	10000/Tape&Reel

3. MAXIMUM RATINGS(Ta = 25ºC)

Parameter	Symbol	Limits	Unit
Drain–Source Voltage	VDSS	-50	V
Gate–to–Source Voltage – Continuous	VGS	±20	V
Drain Current – Continuous TA = 25°C – Pulsed (tp≤10μs)	 ID IDM	 -130 -520	mA

4. THERMAL CHARACTERISTICS

Parameter	Symbol	Limits	Unit
Total Device Dissipation, FR−5 Board (Note 1) @ TA = 25ºC Derate above 25ºC	PD	225 1.8	mW mW/ºC
Thermal Resistance, Junction–to–Ambient(Note 1)	RΘJA	556	ºC/W
Junction and Storage temperature	TJ,Tstg	−55~+150	° C
Maximum Lead Temperature for Soldering Purposes, for 10 seconds	TL	260	ºC

1. FR–5 = 1.0×0.75×0.062 in.

5. ELECTRICAL CHARACTERISTICS (Ta= 25°C)

OFF CHARACTERISTICS

Characteristic	Symbol	Min.	Typ.	Max.	Unit
Drain–Source Breakdown Voltage (VGS = 0, ID = -250μA)	VBRDSS	-50	-	-	V
Zero Gate Voltage Drain Current (VGS = 0, VDS = -25 V) (VGS = 0, VDS = -50 V) (VGS = 0, VDS = -50 V,TJ=125°C)	IDSS	- - -	- - -	-0.1 -15 -60	μA
Gate–Body Leakage Current, Forward (VGS = 20V)	IGSSF	-	-	10	μA
Gate–Body Leakage Current, Reverse (VGS = - 20V)	IGSSR	-	-	-10	μA

ON CHARACTERISTICS (Note 2)

Gate Threshold Voltage (VDS = VGS, ID = -250μA)	VGS(th)	-0.8	-	-2	V
Static Drain–Source On–State Resistance (VGS = -5.0 V, ID = -100 mA) (VGS = -10 V, ID = -100 mA)	RDS(on)	- -	2 1.8	6 5	Ω
Transfer Admittance (VDS = -25 V, ID = -100 mA, f = 1.0 kHz)	|yfs|	50	-	-	mS

DYNAMIC CHARACTERISTICS

Input Capacitance (VDS = - 15V,VGS=0V,f=1MHz)	Ciss	-	38	-	pF
Output Capacitance (VDS = - 15V,VGS=0V,f=1MHz)	Coss	-	4.8	-	pF
Reverse Transfer Capacitance (VDS = - 15V,VGS=0V,f=1MHz)	Crss	-	2.7	-	pF

SWITCHING CHARACTERISTICS

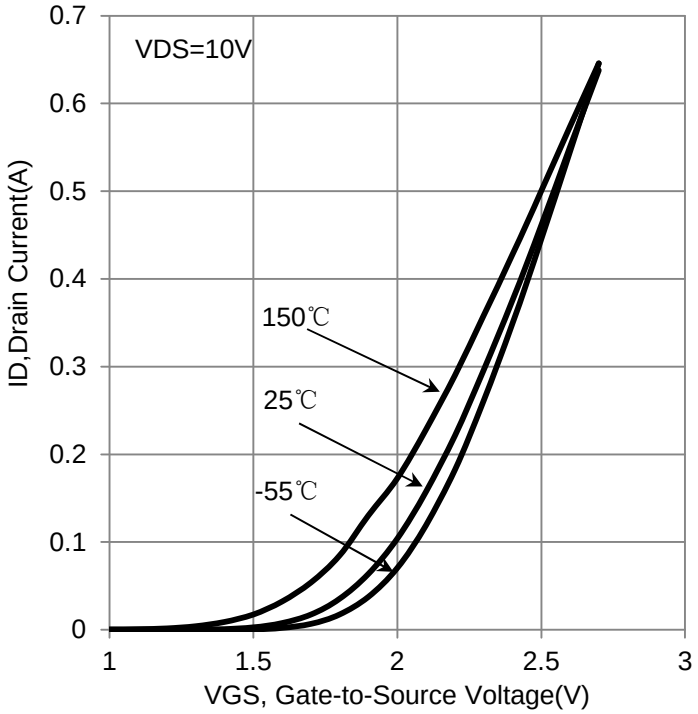
Turn-On Delay Time	(VDS = –15 V,VGS=-10V ,RL = 50Ω,RG=25Ω)	td(on)	-	16.7	-	ns
Rise Time		tr	-	8.6	-	
Turn-Off Delay Time		td(off)	-	17.9	-	
Fall Time		tf	-	5.3	-	

SOURCE–DRAIN DIODE CHARACTERISTICS

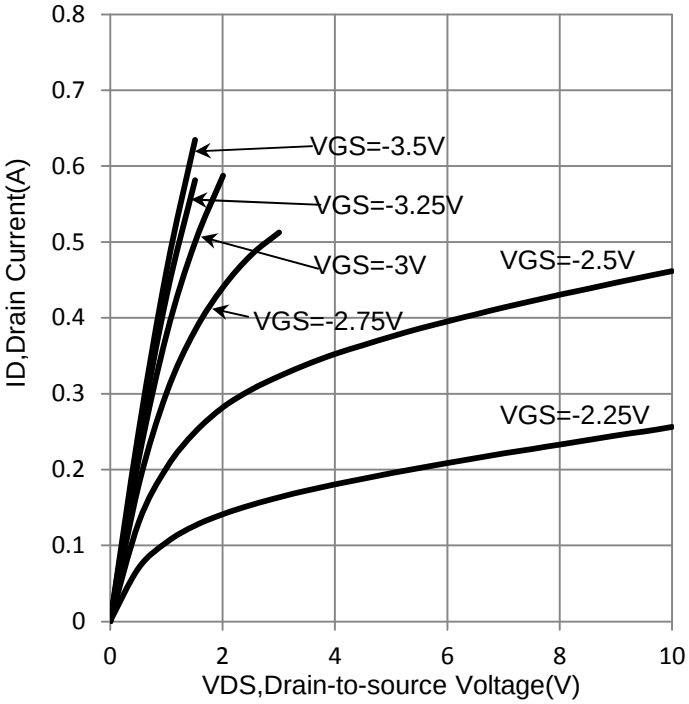
Continuous Current	IS	-	-	-0.13	A
Pulsed Current	ISM	-	-	-0.52	A
Forward Voltage	VSD	-	-2.5	-	V

2.Pulse Test: Pulse Width ≤300 μs, Duty Cycle ≤2.0%.

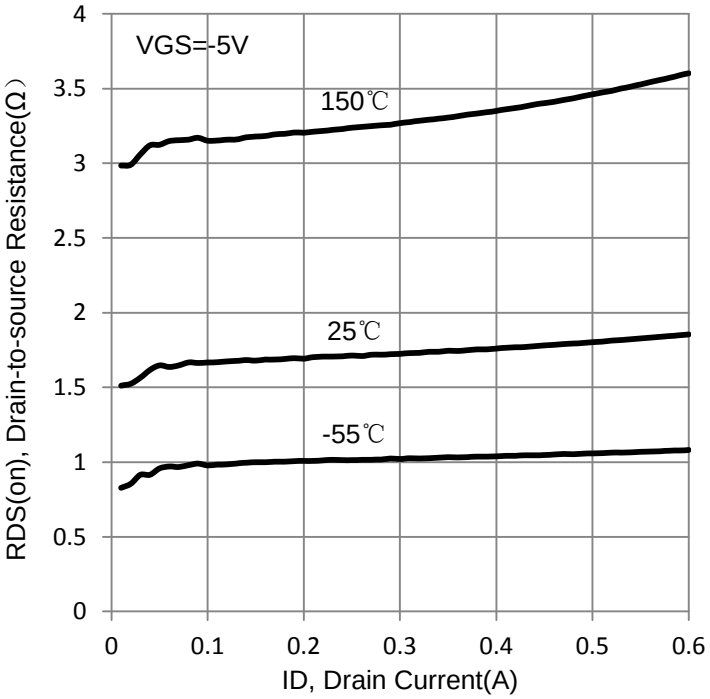
6. ELECTRICAL CHARACTERISTICS CURVES



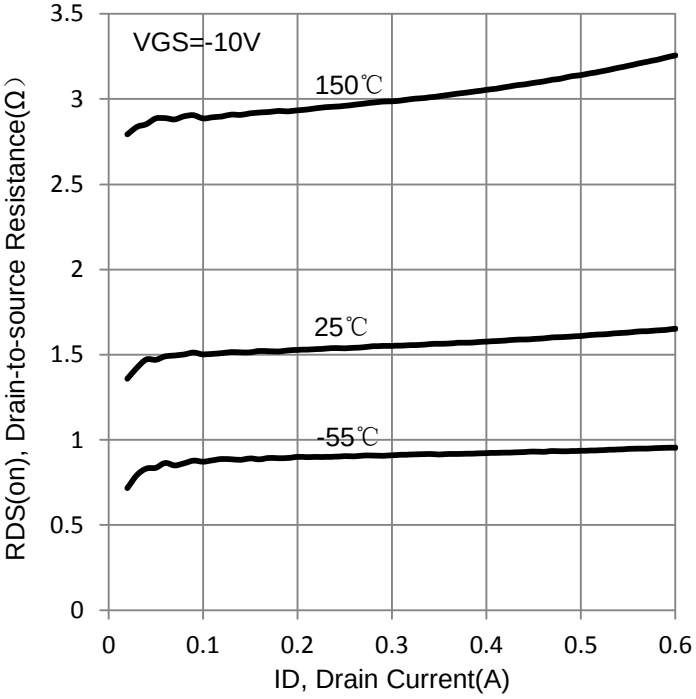
Transfer Characteristics



On-Region Characteristics

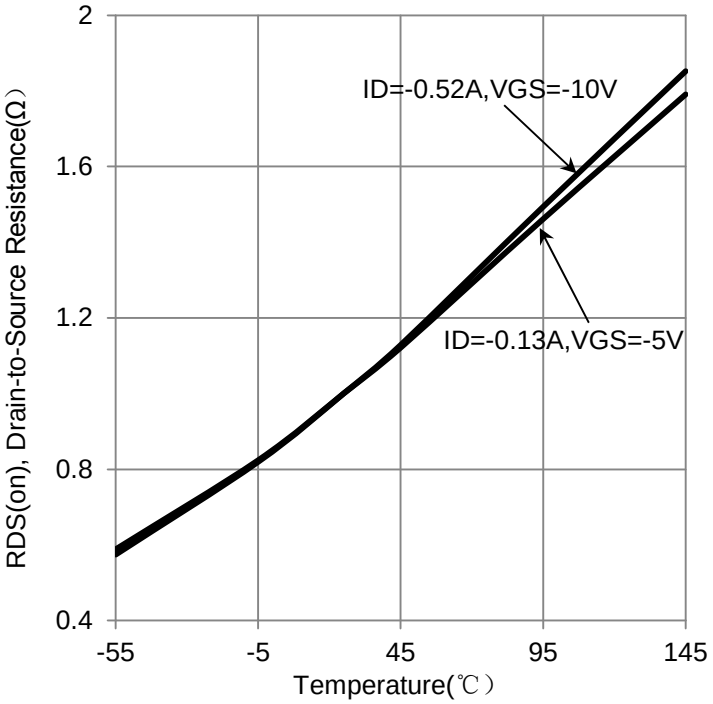


RDS(on) vs. ID

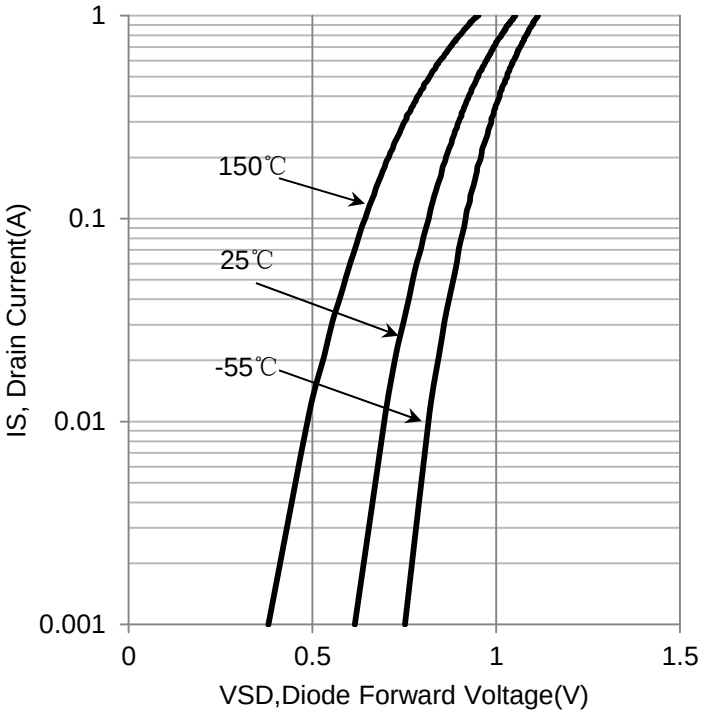


RDS(on) vs. ID

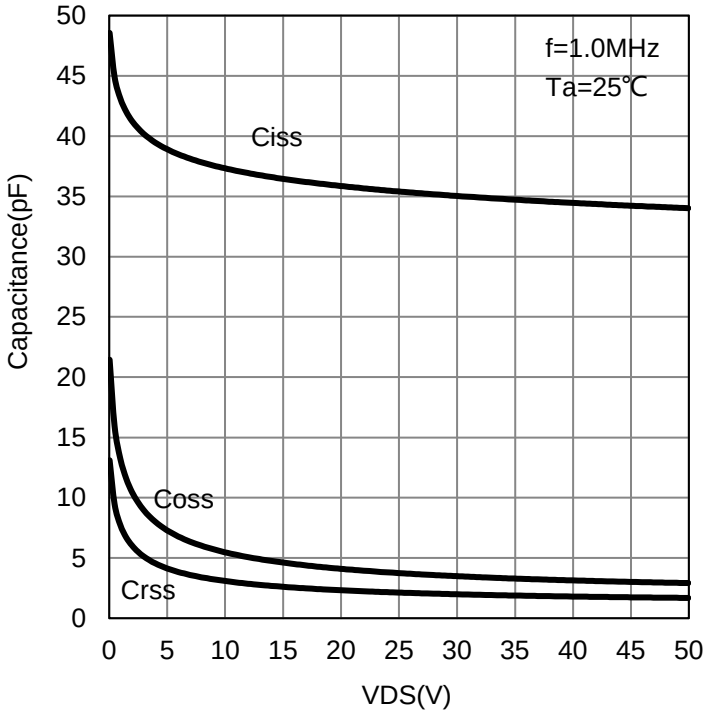
6. ELECTRICAL CHARACTERISTICS CURVES(Con.)



RDS(on) vs. Temperature

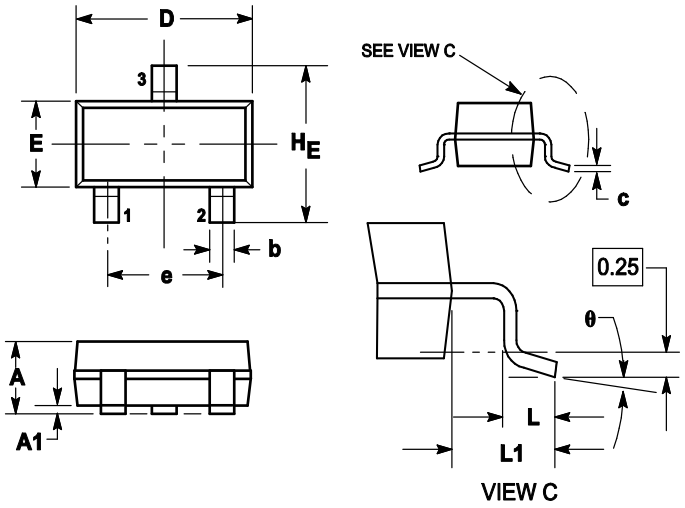


IS vs. VSD



Capacitor vs. VDS

7.OUTLINE AND DIMENSIONS

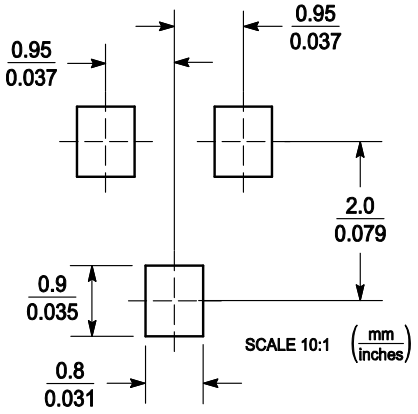


Notes:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
A	0.89	1	1.11	0.035	0.04	0.044
A1	0.01	0.06	0.1	0.001	0.002	0.004
b	0.37	0.44	0.5	0.015	0.018	0.02
c	0.09	0.13	0.18	0.003	0.005	0.007
D	2.80	2.9	3.04	0.11	0.114	0.12
E	1.20	1.3	1.4	0.047	0.051	0.055
e	1.78	1.9	2.04	0.07	0.075	0.081
L	0.10	0.2	0.3	0.004	0.008	0.012
L1	0.35	0.54	0.69	0.014	0.021	0.029
H_E	2.10	2.4	2.64	0.083	0.094	0.104
θ	0°	---	10°	0°	---	10°

8.SOLDERING FOOTPRINT



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